NSN 5961-01-378-5895

Diode Semiconductor Device - Page 1 of 1



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Overall Length:
Between 0.325 inches and 0.335 inches
Features Provided:
Electrostatic sensitive and hermetically sealed case
Semiconductor Material:
Silicon
Power Rating Per Characteristic:
50.0 milliwatts small-signal output power, common-base minor
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

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